

The Structure Analysis of β -Rhombohedral Boron†

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A detailed discussion of the analysis of the structure of β -rhombohedral boron, β -B₁₀₅, is presented. Several formulations of the icosahedral framework structure are fully elaborated and detailed variations in bond lengths and bonding geometries are discussed. Perturbations of the ideal structure are effected through partial occupancies, substitutional atoms, and local disorders in framework and interstitial sites.

Introduction

Although detailed structure analyses have been reported for only three of the dozen or more proposed polymorphic forms of boron, evidence is steadily accumulating in support of the contention (1) that β -rhombohedral boron is the thermodynamically stable polymorph. The first structure to be determined was that of α -tetragonal boron or α -B₅₀ (2, 3). It now appears that this is a self-sustaining framework based upon a boride structure, MB₂₅. The complex framework is probably stable over the entire composition range M_xB₂₅ with $0 \leq x \leq 1$. The second structure to be reported was the remarkably simple α -rhombohedral boron or α -B₁₂ (4). It has been suggested (1) that this is a monotropic form of the element, stable only under specialized conditions. The third structure to be reported was that of β -rhombohedral boron or β -B₁₀₅; the basic structure was presented in a brief report (5) and was further amplified in subsequent discussions (1, 6). The details of the analysis of this important structure are presented herein; none of the essential features of the structure given earlier are modified in this final formulation.

Experimental

Crystalline specimens of elementary boron of a stated purity of 99.4% were kindly provided by the Bell Telephone Laboratories through the courtesy of Dr. S. Geller. These had been prepared from

rather pure amorphous boron supplied by Cooper Metallurgical Associates by crystallization from the melt under an atmosphere of helium in a Heliarc furnace. Other samples, specified as 99.5% pure boron, were kindly provided by the United States Borax and Chemical Corporation; data recorded from single crystal fragments from these fused pellets were used in the final structure analysis. This boron was prepared from the reduction of boric oxide with magnesium metal and subjected to a mixed fluoride flux at about 1000°C, after which most of the residual impurities were removed by vacuum sublimation at or near the melting point of boron ($2250 \pm 50^\circ\text{C}$). The difficulties involved in the preparation and purification of boron have been carefully explored in recent years (see, for example, 6, 7), and it appears that this procedure can yield the element at the stated level of purity if sufficient care is taken to exclude such tenacious contaminants as Al, Si, C, Mn, Fe, etc., at every stage of the preparation (8). In the present case, the impurity content was formally expressed in terms which correspond to addition of approximately ten magnesium atoms, three atoms of aluminum and one each of silicon, iron and manganese to the 8400 boron atoms of 80 unit cells. This is equivalent to an average of one-fifth of an impurity atom in each unit cell containing 105 boron atoms. Precise, quantitative determination of the detailed impurity concentrations in such a system is, at best, a difficult analytical task; nevertheless, utilizing the basic boron framework structure reported herein as a standard, it is possible to assess the partial occupancy of interstitial and substitutional impurity sites from a detailed analysis of the diffraction data.

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This analysis (*vide infra*) suggests that the crystals used had somewhat higher impurity levels than was estimated by the supplier; no specific identification of impurities is possible, but magnesium and aluminum would appear to be the most likely metallic candidates.

Visual comparison of the X-ray diffraction patterns of crystals from these different preparations revealed no significant differences in the spacings, in the intensity distributions or in the character of the reflections beyond the minor variations associated with the uneven quality of different crystal fragments. There is little doubt, of course, that a detailed statistical treatment of all of the intensity data from the several crystals would reveal the small but systematic variations which must attend even minor differences in impurity concentrations. But, more to the point, there appears to be no reason to assume that the analysis of data even from an *ultrapure* sample would in any way vitiate the conclusions drawn herein about the basic three-dimensional framework of boron atoms; rather, we expect that the stability of the structure is such that it can accommodate a rather substantial concentration of specific impurities with only modest changes in bond lengths and local order.

The X-ray diffraction parameters derived from a careful analysis of $\text{CuK}\alpha$ data obtained on various samples on a General Electric XRD-3 spectrogoniometer were reported in an earlier communication (9) and the material was characterized as the β -rhombohedral polymorph of elementary boron. The rhombohedral lattice parameters are $a = 10.145 \pm 0.015 \text{ \AA}$ and $\alpha = 65^\circ 17' \pm 8'$ and the corresponding triply primitive hexagonal cell parameters are $a_h = 10.944 \pm 0.015 \text{ \AA}$ and $c_h = 23.81 \pm 0.03 \text{ \AA}$.

The density of the material used in the structure analysis was determined to be 2.35 g/cc by a flotation measurement. If the primitive cell contained *only* boron atoms, the number, Z_B , would be determined by the density in the expression $Z_B = 45.87 \rho$. Thus, the observed density would correspond to 108 boron atoms per unit cell; conversely, the basic framework described below involves only 105 boron atoms per repeating unit and would, therefore, correspond to an idealized crystal density of 2.29 g/cc. These observations are partially reconciled in a subsequent discussion of interstitial and substitutional solid solution in the boron framework.

In the absence of any systematic extinctions, the observed diffraction symmetry of the rhombohedral lattice was compatible with any one of the three space groups, $R3m$, $R\bar{3}m$, $R32$. Statistical analyses

of intensity distributions according to the formulations of Wilson (10) and of Howells, Phillips, and Rogers (11) produced equivocal results which were readily attributable to a hypercentric distribution and pseudosymmetry after the structure was solved. The distribution of peak density in Patterson space (12) was not inconsistent with $R\bar{3}m$ and a sensitive capacitance measurement in a varying field failed to detect the slightest piezoelectric signal. Thus, understandably, the choice inevitably devolved to the centrosymmetric space group $R\bar{3}m$; the results of the structure analysis fully support this assumption, *post facto*.

Integrated intensities were measured on the spectrogoniometer from a stationary crystal with converging beam geometry. A diffractometer take-off angle of 7° ensured that a reasonable mosaic angle was subtended by the source focal spot at every point on a crystal of over-all dimensions of 0.15–0.20 mm. After preliminary scanning to screen out very low level or absent reflections, peak intensities were recorded on a fixed count basis with a krypton filled proportional counter. Background corrections were evaluated from the systematic application of carefully calibrated, balanced Ross filters to each peak intensity measurement. For $\text{Mo K}\alpha$ radiation, these filters were prepared from zirconium foil and from homogeneous films fabricated from yttrium oxide and binders; nickel-cobalt filters were used for $\text{Cu K}\alpha$ radiation.

An empirically determined linear interpolation correction was applied as a function of angle to account for the $\text{K}\alpha_1$ – $\text{K}\alpha_2$ dispersion observed with both copper and molybdenum radiation. No corrections were applied either for extinction or absorption; the latter is utterly negligible and the former is at best, uncertain in a structure of this hardness and complexity. It would be appropriate to consider the difficult question of extinction corrections in any future elaborate refinement of data from an *ultrapure* crystal. Standard polarization factors were applied and Lorentz factors were used to account for the equivalent quasirotation through the mosaic angle in the converging beam.

All reflections accessible in the full 2θ range of the spectrogoniometer were measured with $\text{Cu K}\alpha$ radiation. The range of these measurements was extended with $\text{Mo K}\alpha$ radiation and the data sets were combined in a very satisfactory statistical cross-calibration of overlap measurements. This procedure yielded a total of 1445 reflections. As a result of the small size of the crystal, a falloff in quality of these data with increasing angle was evident and, in the final refinement of the structure, an arbitrary cutoff

was applied at $2\theta \leq 70^\circ$ (Mo $K\alpha$); this circumscribed a total of 921 reflections in a volume approximately twice that of the Cu $K\alpha$ sphere in reciprocal space.

Discussion of the Analysis

A three-dimensional Patterson function was calculated and, predictably for a structure with more than one hundred identical atoms per unit cell, was not subject to unambiguous interpretation. Nevertheless, ill defined concentric shells of density, while not definitive, were consistent with the presence in the structure of icosahedra of boron atoms. The unique role of this extraordinary structure element in the crystal chemistry of boron and the higher borides had already begun to emerge from a consideration of the icosahedral structures of boron carbide (13) α -tetragonal boron (2, 3) and α -rhombohedral boron (4). Moreover, the basic metrics and characteristic angles of this structure element were imbedded in the pseudocubic geometry of the β -rhombohedral lattice in a way which suggested

some complex stellation or tessellation of the boron carbide framework structure.

A systematic application of direct statistical methods was clearly indicated and a subsequent extension of early results did indeed ultimately lead to the correct structure (14). However, at an early stage, the analysis suddenly yielded to a framework model which was derived from a stereochemical analysis of boron bonding. The framework was based upon the union of complex 84-atom structure elements which (in slightly idealized form) displayed full icosahedral symmetry and which played a role analogous to that of the icosahedron in the boron carbide structure. Fourier syntheses based upon this B_{84} unit quickly revealed additional atoms and the full framework of 105 atoms emerged from a systematic iteration of Fourier and least-square analyses (5).

The final refinement was based upon a least-squares fit of the 921 independent reflections for which 2θ (Mo $K\alpha$) $\leq 70^\circ$. A total of 65 parameters, including coordinates, individual isotropic atomic

TABLE I

FINAL COORDINATES, TEMPERATURE FACTORS AND STANDARD DEVIATIONS FROM LEAST-SQUARES REFINEMENT OF 921 REFLECTIONS AT $2\theta(\text{MoK}\alpha) \leq$ WITH CONVENTIONAL. $R = 0.098$

| B (n) | Hexagonal fractional coordinates x, y, z and standard deviations $\sigma_x, \sigma_y, \sigma_z$ ($\times 10^4$) | | | | | | Isotropic temp. factor | | Electron density ^a $e/\text{\AA}^3$ |
|-------|---|------------|--------|------------|---------|------------|------------------------|------------|---|
| | x | σ_x | y | σ_y | z | σ_z | B (\AA^2) | α_B | |
| 1 | 0.1730 | 3 | 0.1742 | 3 | 0.1768 | 1 | 0.485 | 0.052 | 26 |
| 2 | 0.3189 | 3 | 0.2966 | 3 | 0.1291 | 1 | 0.538 | 0.053 | 23 |
| 3 | 0.2607 | 3 | 0.2172 | 3 | 0.4199 | 1 | 0.479 | 0.053 | 24 |
| 4 | 0.2351 | 3 | 0.2506 | 3 | 0.3473 | 1 | 0.624 | 0.054 | 23 |
| 5 | 0.0549 | 2 | 0.1097 | 2 | -0.0560 | 2 | 0.551 | 0.062 | 31 |
| 6 | 0.0867 | 2 | 0.1735 | 2 | 0.0130 | 2 | 0.613 | 0.067 | 24 |
| 7 | 0.1091 | 2 | 0.2182 | 2 | -0.1140 | 2 | 0.470 | 0.061 | 26 |
| 8 | 0.1703 | 2 | 0.3406 | 2 | 0.0281 | 2 | 0.623 | 0.064 | 21 |
| 9 | 0.1285 | 2 | 0.2570 | 2 | -0.2338 | 2 | 0.569 | 0.064 | 27 |
| 10 | 0.1022 | 2 | 0.2044 | 2 | -0.3020 | 2 | 0.348 | 0.062 | 25 |
| 11 | 0.0562 | 2 | 0.1125 | 2 | 0.3267 | 2 | 0.414 | 0.061 | 26 |
| 12 | 0.0894 | 2 | 0.1788 | 2 | 0.3990 | 2 | 0.353 | 0.062 | 27 |
| 13 | 0.0574 | 3 | 0.1148 | 3 | -0.4460 | 2 | 0.780 | 0.088 | 17 |
| 14 | 0.0000 | 0 | 0.0000 | 0 | 0.3852 | 3 | 0.272 | 0.087 | 27 |
| 15 | 0.0000 | 0 | 0.0000 | 0 | 0.5000 | 0 | 1.315 | 0.160 | 20 |
| 16 | 0.0546 | 9 | 0.1093 | 9 | 0.1166 | 6 | 1.944 | 0.239 | 7 |

^a Peak density is at nearest grid coordinate and is not the highest value at maxima.

temperature factors and a scale factor, were fixed by the analysis; coordinate relationships in special positions, assumed in the final refinements, reduced this number to a total of 51 independent variables in the least-squares analysis. This entirely satisfactory data-parameter ratio of 19 provided a conventional discrepancy index of $R = 0.098$ for the coordinates and temperature factors listed in Table I. The final values for the calculated structure factors are compared with the observed data in Table II. Utilizing the same set of coordinates in a calculation involving the total 1445 reflections observed out to 2θ ($\text{MoK}\alpha$) $\approx 140^\circ$, produced a value of $R = 0.129$. This rather reasonable increase in R was accompanied by an increase of almost 50% in the standard deviations of the atom coordinates; simultaneously, an average decrease of about 25% was observed in the atomic temperature factors and in their associated standard deviations.

As the refinement progressed, Fourier synthesis and difference syntheses were used to corroborate the least-squares analyses. It became apparent that an unusually high temperature factor ($B = 2.4 \text{ \AA}^2$) for atom B (13) could more plausibly be interpreted in terms of a partial occupancy of the site. It can be seen from the peak densities of the final Fourier syntheses reported in the last column in Table I that the B (13) site occupancy factor of two-thirds used in the final least-squares analysis was entirely appropriate. Moreover, the corresponding temperature factor is more reasonable in terms of structural constraints which will be discussed below. Similarly, a second major site of partial occupancy lies at B (16); consistent with the low Fourier peak density recorded for this atom in Table I, an occupancy factor of one-third was used in the final least-squares analysis. The relatively high temperature factor suggests that there is residual structural disorder in this local region or, possibly, some impurity concentration uncompensated in the atomic scattering factor. Finally, the high temperature factor and the slightly reduced peak density at B (15), while not sufficiently atypical to warrant a special occupancy parameter, suggest that this site is a vulnerable one.

The characterization of inherent disorders and of partial occupancies in framework sites and in interstitial sites in icosahedral framework structures is of fundamental importance, not only to the understanding of the disposition of impurity atoms in boron, but also to the development of detailed structural mechanisms of boride formation and indeed, to the study of the electronic properties of icosahedral bonding. Nevertheless, an essential point must not be obscured by the enhanced agree-

ment which can be obtained by coupling Fourier analyses with least-squares refinements through site occupancy factors. Given a basic structure, the parameters which can be varied to improve the statistical agreement between the observed and calculated structure factors are strongly correlated. Essentially the same results can be achieved from any number of reasonable combinations of atomic form factors, atomic temperature factors and site occupancy factors. It is obvious that appropriate atomic scattering factors can be chosen only with an a priori knowledge of the detailed stoichiometry—information which is rarely available with any precision for the many impurity atoms that occur in boron and boride structures. Moreover, even if the impurity atom or the boride forming element is known or assumed, the stoichiometry can be deduced from the diffraction data only after further assumptions are made concerning the correlation between partial site occupancies and local disorder at or near the sites. It is clear that the number of degrees of freedom in such an analysis rises sharply when multiple sites and more than one kind of impurity atom are involved.

Each independent experimental constraint imposed upon such an analysis is of great value. In addition to precise measures of stoichiometry and density, one can contemplate the use of anomalous dispersion measurements in appropriate circumstances. Of greatest value would be a carefully calibrated series of single crystal studies on systems of continuously varying composition.

In icosahedral framework structures it is essential that a clear differentiation be made between framework and interstitial sites. In each case the framework must be specified in complete geometric detail as that irreducible connexity of covalent linkages which defines the ideal structure. This requirement so straightforward in such familiar structures as those of diamond, wurtzite, MB_6 and MB_{12} , involves surprisingly subtle issues in complex boron and icosahedral boride structures. This is due in part to the rather large holes which are bounded by the compact icosahedral groupings and, in part, to the anomalous (or, at least, ambiguous) role played by individual atoms or groups of atoms in filling in unique connexities in the structure. Simple examples of the latter would include the tetrahedrally bonded boron atom in the tetragonal $\alpha\text{-B}_{30}$ structure, the tetrahedrally bonded carbon atoms in boron carbide (B_{11}C)CBC and the unique boron atom in the center of the cell in the present structure of β -rhombohedral boron. Most, but by no means all, framework atoms in the known structures are boron; the precise

status of other elements may be difficult to determine, especially in systems displaying variable stoichiometry. For example, the exact role of aluminum in the family of boride and ternary borocarbide structures will require thoughtful consideration and careful argument.

It appears that many framework sites are subject to at least three kinds of structural perturbations. The first and simplest involves direct substitution of impurity atoms or boride forming elements for framework atoms in selected icosahedral and non-icosahedral sites. The arbitrary distinction drawn between the two kinds of substitutional atoms is purely operational; a substitutional (or interstitial) atom is deemed to be a boride forming atom when its location corresponds in some structurally significant way to its state in a known boride structure. Secondly, depending upon local bonding geometries and crystal growth conditions, some framework sites can exhibit partial occupancy, even in pure boron. Finally, certain framework sites are subject to structural disorder, especially those in the neighborhood of substituted sites and partially occupied interstitial sites.

In contrast to framework sites, interstitial sites are subject to the thermodynamically significant constraint that the lattice constants of the host phase are essentially unaltered by the inclusion of an interstitial component. It is clear that numerous holes in icosahedral framework structures are accessible to impurity atoms, to boride forming atoms and, as well, to extra boron atoms; moreover, partial occupancy of such sites is also to be expected. In addition, some of the holes are sufficiently large to provide more than one equilibrium position for the entrapped atom; the attendant statistical disorder serves to further mask the relationships between occupancy factors and atomic form factors in a detailed diffraction analysis.

The weight of the foregoing observations is largely anticipatory although some of the factors discussed were considered in detail in the analysis of the icosahedral structure of α -tetragonal boron (3). In the present analysis, only two site occupancy factors are involved; one characterizes partial occupancy of a site which is clearly in the framework (vide infra) and the other, of a site which is deemed interstitial. The analysis, which completely delineates the framework and explores the occupancy of all of the probable interstitial sites, extracts essentially all of the unequivocal information residing in the data. Nevertheless, it will be seen that a curious ambiguity remains in the interpretation of the crystal density. It is clear that in future it will be necessary to care-

fully expose all of the assumptions imbedded in diffraction analyses as, inevitably, detailed structural mechanisms are invoked to explain the extraordinary proliferation of boron polymorphs and nonstoichiometric icosahedral borides. These observations suggest that it would be useful to collect data from carefully annealed samples of the ultrapure boron now available in order to establish the electron density levels and temperature factors against which the state of impurities in quantitatively doped crystals might be calibrated. This program is underway, but in the absence of such data, the present analysis provides the basic structural framework and, as well, some measure of the sites at which localization of impurities and disorder might occur.

Discussion of the Structure

All of the essential elements of the structure deduced from the present analysis have been described in some detail elsewhere (1, 5, 14); for present purposes, a brief description will provide sufficient background for the presentation of all of the important bonding parameters.

A three-dimensional framework structure can be faithfully described in remarkably diverse but nevertheless complementary ways, each one of which illuminates different aspects of the structure. A description based upon the bonding geometry around each type of atom is often appropriate; alternatively, the corresponding space-filling coordination polyhedra can be used. Polyhedral constellations of atoms often reveal correlations among related structures in the various ways they link together or share vertices, edges and faces or, more subtly, in the ways they interpenetrate. Because the β -rhombohedral boron structure is moderately complex, it is useful to consider alternate descriptions based upon different building blocks. The present discussion will be restricted to linked arrays of three different icosahedral subunits, the B_{12} unit, the B_{84} unit and the B_{156} unit.

The simplest formulation of the β - B_{105} structure is provided by an analogy (1) to the well-known boron carbide structure, $(B_{11}C)(CBC)$. This rhombohedral structure, $R\bar{3}m$, is based upon a lattice which is approximately face-centered cubic; indeed, if the angle listed in Table III were 60° , the geometry, but not the symmetry, of the structure would be exactly FCC. The structure consists of a single icosahedron at each lattice point, oriented with a threefold axis along the rhombohedral direction; a linear CBC chain lies along the axis with the boron atom at the

TABLE III
RHOMBOHEDRALLY LINKED ICOSAHEDRAL FRAMEWORK STRUCTURES BASED UPON
 $R\bar{3}m$

| | a (Å) | α | |
|------------------------------|-------|----------------|---|
| $B_{12}(1.80 \text{ \AA})^a$ | 5.22 | $63^\circ 26'$ | Hypothetical Structure |
| $\alpha\text{-}B_{12}$ | 5.06 | $58^\circ 4'$ | α -Rhombohedral Boron |
| $(B_{11}C)(CBC)$ | 5.17 | $65^\circ 36'$ | Boron Carbide, B_4C |
| $(B_{84})(B_{10}BB_{10})$ | 10.14 | $65^\circ 17'$ | β -Rhombohedral Boron, $\beta\text{-}B_{105}$ |

^a Hypothetical rhombohedral framework structure of ideally linked perfect icosahedra of edge length 1.80 Å.

center of the cell and the carbon atoms near the interfaces between the central octahedral hole and the adjacent tetrahedral holes. The orientation of the icosahedra can be visualized by considering the hypothetical structure $B_{12}(1.80)$ listed in Table III. Six of the 12 atoms in the perfectly regular icosahedron in this structure are in a very flat triangular antiprism which forms a slightly puckered ($10^\circ 50'$) equatorial belt around the threefold axis. The remaining six atoms lie at the vertices of another triangular antiprism which interpenetrates the first. These vertices subtend at the center a rhombohedral vector triplet with $\alpha = 63^\circ 26'$; bonding between adjacent icosahedra is effected radially along these rhombohedral directions to form a tight three-dimensional framework structure. This radial bonding along the quasifivefold axes of boron icosahedra generates the preferred pentagonal pyramidal coordination (I) around each boron atom. The remaining half of the atoms in this structure, the equatorial atoms, are too far apart to form a sixth bond in the preferred coordination geometry; in $\alpha\text{-}B_{12}$, the angle collapses to $58^\circ 4'$ and the equatorial atoms from adjacent icosahedra link around the threefold axes in weak, triangular three-center bonds; in boron carbide, the equatorial atoms bond radially through the interposed carbon atoms on the ends of the central CBC chains.

The analogy between the β -rhombohedral boron and the boron carbide structures is revealed by reformulating $\beta\text{-}B_{105}$ as $(B_{84})(B_{10}BB_{10})$. The B_{84} unit is a quasispherical icosahedral entity which is centered at the lattice points of an approximately face-centered cubic rhombohedral lattice; the $(B_{10}BB_{10})$ chain lies along the threefold axis with the boron atom at the center of the cell and the compact B_{10} units near the interfaces between the

central octahedral and adjacent tetrahedral holes. The B_{84} unit can be derived by stellating an icosahedron with 12 half-icosahedra; the six-atom pentagonal caps can be oriented to preserve full icosahedral symmetry for the whole unit. Alternatively, the unit can be derived by inserting two concentric icosahedra into the 60-atom shell pictured in Fig. 1. The 60-atom unit derives from the truncation of a regular icosahedron; each of the 12 vertices becomes a pentagon and each of the 20 triangular faces becomes a hexagon. The full B_{84} unit is depicted in Fig. 2.

The rhombohedral linkages between adjacent B_{84} units are effected through the juxtaposition of pentagonal caps rather than through the direct

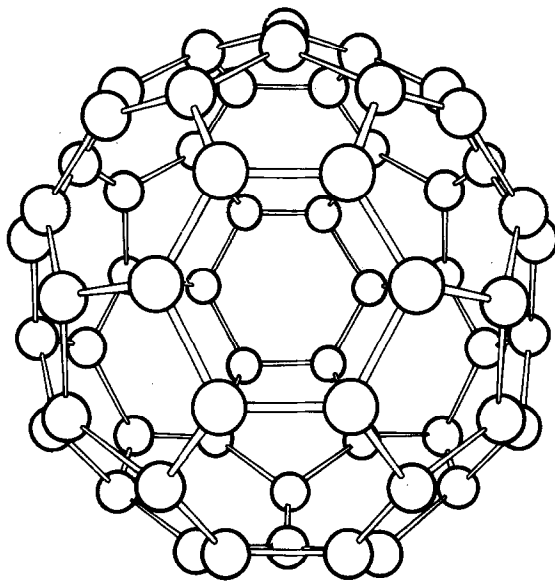


FIG. 1. A perspective view along the threefold axis of a 60-atom truncated icosahedron.

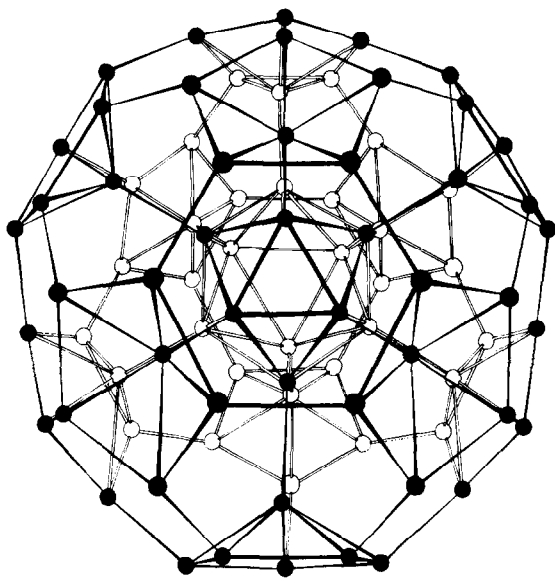


FIG. 2. A perspective view along the threefold axis of a B_{84} unit. Rhombohedral linkages between B_{84} units are effected through the juxtaposition of the half-icosahedra visible at the surface.

radial bonding found in the boron carbide structure. This juxtaposition produces, in each instance, a B_{12} icosahedron from the two half-icosahedra and thereby creates a framework structure with a high percentage of the preferred pentagonal pyramidal coordination.

The linkages between the equatorial pentagonal caps on adjacent B_{84} units are effected through the B_{10} units depicted in Fig. 3. When considered in conjunction with the three surrounding pentagonal caps this unit is clearly derived from the condensation of three B_{12} icosahedra around a threefold axis. One atom on the axis is shared by all three icosahedra.

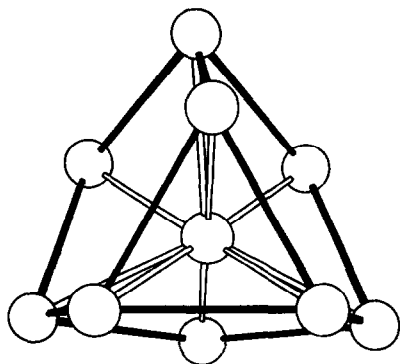


FIG. 3. The B_{10} subunit derived from the partial condensation of three icosahedra. Equatorial linkages between adjacent B_{84} units are generated through the pentagonal faces of this subunit.

hedra, six other atoms are shared between pairs of icosahedra and the remaining three are unshared. These remarkable B_{10} units are linked through the boron atom at the center of the cell.

An alternative description of the structure can be based upon the B_{156} unit derived by completely stellating the pentagonal faces of the B_{84} unit with half-icosahedron caps. This array of 12 B_{12} units around a central (slightly smaller) icosahedron displays full icosahedral symmetry. Placed at the lattice points of the rhombohedral cell it completely reproduces the entire structure, except for the single boron atom at the center of the cell. The rhombohedrally directed icosahedra between adjacent B_{156} units overlap completely and identically; the equatorially directed icosahedra overlap partially to form the B_{10} units described above. Other connectivities between B_{156} units are of interest in higher boride structures.

Emphasis can be placed upon B_{12} units in another description of the structure based upon linear chains of icosahedra radially bonded along quasifivefold axes coincident with the rhombohedral cell axes. In each chain, adjacent icosahedra are related by a rotation of $2\pi/10$ and a translation of $a/2$. The large holes in this rhombohedrally linked framework are filled by the B_{28} unit derived from the partial condensation of three icosahedra around the threefold axis. This, of course, is the B_{10} unit with three half-icosahedra added to its three pentagonal faces.

It should be emphasized, in every case, that the compact quasispherical structural units link together in a strong three-dimensional covalently bonded framework. This combination of compact units and strong, directed covalent bonding creates a structure with many holes; in the B_{84} unit, for example, each of the 20 hexagonal faces caps a truncated tetrahedron which is large enough to accommodate an extra atom; and even larger holes exist between the units. The distribution of extra boron atoms and other impurity atoms in these holes undoubtedly contributes to anomalies observed in the density of the crystal. Occupancy of selected sites also provides the driving force for the formation of related boride structures.

None of the icosahedral structural units described above are perfectly regular, but the distortions which do occur are modest, and it is convenient to preserve the concept of regular icosahedral symmetry in all general descriptions of the structure. Nevertheless, a careful study of the deviations which do occur is essential in any analysis of the relationships among boron and boride structures.

The central icosahedron in the B_{84} units located

at the origin is very nearly regular. The slight distortion which does occur involves a constriction around the equatorial belt where the average bond length is 1.75 Å (B6–B6). The rhombohedral atoms, B5, are bonded at 1.80 Å and the over-all average bond length is 1.767 Å.

The icosahedra located at the mid-edges of the cell involve atoms B1, B2, B7, and B9. These are nearly regular with an average bond length of 1.85 Å; however, the B1–B1 bond is substantially longer than the average at 1.92 Å. In the B_{84} unit, this bond is in the hexagon at the poles through which the threefold axis passes. The remaining (B1–B1, intericosahedral) link in this hexagon is also unusually long (1.88 Å). This dilation is a magnification of the distortion observed in the central icosahedron. The rhombohedrally directed intericosahedral bond between icosahedra centered at the origin and mid-edge is typically short (1.72 Å); this corresponds to the general observation (1) that interpolyhedral bonds are shorter than intrapolyhedral bonds in boron systems.

The triply condensed icosahedral B_{28} unit (which contains the B_{10} unit) girdles the equator of the B_{84} unit. In this unit, atoms B11 and B12 are shared between pairs of adjacent icosahedra and atom B14 is shared by all three. The coordination of B11 and B12 is eightfold while that of B14 is ninefold; all of the other atoms in the structure display sixfold coordination with one radial intericosahedral and five intraicosahedral bonds, except for B15 which is in a trigonal antiprism at the cell center.

The condensed icosahedra in the B_{28} unit display significant distortions from regularity. Most of the bond lengths range from 1.76–1.85 Å but B3–B3 is significantly longer at 1.90 Å and B4–B8 is significantly shorter at 1.725 Å; the over-all average of 1.81 Å is remarkably close to the usual value for intraicosahedral boron bonds.

The intericosahedral links joining the B_{28} unit into the equatorial belt of the B_{84} unit average 1.71 Å and the links to the central icosahedron are only 1.624 Å. Consequently, the B_{84} unit is markedly prolate with slightly large hexagonal openings at top and bottom.

In the B_{28} unit, atom B13 is located sufficiently close to the threefold axis that the B13–B13 distance is only 1.885 Å. This is close enough to represent a rather strong bond; the three-center bond in α - B_{12} is 2.025 Å. It appears from the analysis that an occupancy factor of two-thirds should be applied to this

site. This suggests that only two of the three positions can be occupied in any unit cell. This conjecture is supported by the fact that the bond distance between B13 and the atom at the center of the cell, B15, is only 1.684 Å; ~~it seems unlikely that a boron atom would form six short octahedral bonds to other boron atoms.~~

Finally, the B16 atoms are situated in the mirror planes of the cell within that truncated tetrahedral hole in the B_{84} unit which is intersected by the obverse rhombohedral cell faces. The interstitial atom appears to be located near the hexagonal face of the hole rather than at the centroid. The radius of the maximum insertable sphere is 1.115 boron radii (0.90 Å). The site occupancy factor derived from the least-squares and Fourier analyses was one-third of a boron atom. A detailed exploration of all other holes in the structure failed to reveal any major degree of occupancy.

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